

Superior high Flux for High Voltage System

## High-Power LED - 5050 6V Series S1W0-5050xxxx06-00000000-00002











## **Product Brief**

#### **Description**

- This White Colored surface-mount LED comes in standard package dimension.
   Package Size: 5.0x5.0x0.7mm
- It has a substrate made up of a molded plastic reflector sitting on top of a lead frame.
- The die is attached within the reflector cavity and the cavity is encapsulated by silicone.
- The package design coupled with careful selection of component materials allow these products to perform with high reliability

#### **Features and Benefits**

- High Intensity output and high luminance
- Designed for high voltage operation
- SMT solderable
- RoHS compliant
- Color coordinate: 2200K-6500K,CRI70 2700K-6500K,CRI80
- CRI line up 70& 80

#### **Key Applications**

- General lighting
- Architectural lighting
- LED Bulbs
- · Decorative / Pathway lighting

**Table 1-1. Product Selection Table** 

Reference Code	Color	Nominal	Part Number	CRI
Reference Code	Color	ССТ	Fart Number	Min
		6500K	S1W0-5050657006-00000000-00002	
	Co. al 10/16:4a	5700K	S1W0-5050577006-00000000-00002	
	Cool White	5000K	S1W0-5050507006-00000000-00002	
CTMOLODA		4500K	S1W0-5050457006-00000000-00002	70
STW0L8PA	Neutral White	4000K	S1W0-5050407006-00000000-00002	70
		3500K	S1W0-5050357006-00000000-00002	
	\\/arm \\/hita	3000K	S1W0-5050307006-00000000-00002	
	Warm White	2700K	S1W0-5050277006-00000000-00002	
		2200K	S1W0-5050227006-00000000-00002	



#### **Table 1-2. Product Selection Table**

Beforence Code	Calan	Nominal	Part Number	CRI
Reference Code	Color	ССТ	Part Number	Min
		6500K	S1W0-5050658006-00000000-00002	
	Cool White	5700K	S1W0-5050578006-00000000-00002	
		5000K	S1W0-5050508006-00000000-00002	
STW8L8PA	Neutral White	4000K	S1W0-5050408006-00000000-00002	80
		3500K	OK \$1W0-5050358006-00000000-00002	
	Warm White	3000K	S1W0-5050308006-00000000-00002	
		2700K	S1W0-5050278006-00000000-00002	

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## **Product Performance & Characterization Guide**

Table 2. Product Selection Guide, I<sub>F</sub> = 640mA, T<sub>i</sub> = 25°C, RH30%

Min. CRI, Ra <sup>[4]</sup>	Nominal CCT [K] [1]	Min. Flux [lm] @640m A	Typ. Luminous Flux Ф <sub>v</sub> <sup>[2,3]</sup> [lm] @640mA	Typ. Luminous Efficacy [lm/W] @640mA	Part Number	PPF [µmol/s] @640mA	PPE [µmol/J] @640mA
	6500	600	667	168	S1W0-5050657006-00 000000-00002	9.484	3.069
	5700	650	678	171	S1W0-5050577006-00 000000-00002	9.429	3.052
	5000	650	690	172	S1W0-5050507006-00 000000-00002	9.359	3.029
	4500	650	683	172	S1W0-5050457006-00 000000-00002	9.276	2,982
70	4000	650	688	176	S1W0-5050407006-00 000000-00002	9.127	2.954
	3500	600	657	165	S1W0-5050357006-00 000000-00002	8.903	2.881
	3000	600	650	164	S1W0-5050307006-00 000000-00002	8.854	2.864
	2700	550	634	160	S1W0-5050277006-00 000000-00002	8.803	2.849
	2200	500	540	136	S1W0-5050227006-00 000000-00002	8.748	2.831
	6500	600	620	156	S1W0-5050658006-00 000000-00002	9.242	2.991
	5700	600	630	159	S1W0-5050578006-00 000000-00002	9.096	2.944
	5000	600	635	160	S1W0-5050508006-00 000000-00002	8.966	2.913
80	4000	600	635	160	S1W0-5050408006-00 000000-00002	8.811	2.852
	3500	600	615	155	S1W0-5050358006-00 000000-00002	8.682	2.809
	3000	550	610	154	S1W0-5050308006-00 000000-00002	8.563	2.771
	2700	550	595	150	S1W0-5050278006-00 000000-00002	8.465	2.747

#### Notes:

- $\hbox{(1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. } \\$
- (2) Seoul Semiconductor maintains a tolerance of  $\pm 7\%$  on flux and power measurements.
- (3) Photosynthetic Photon Flux (PPF) includes wavelengths between 400 and 700 nm.
- (4) Photosynthetic Photon Efficacy (PPE) includes wavelengths between 400 and 700 nm.



## **Product Performance & Characterization Guide**

Table 3. Characteristics, I<sub>F</sub>=640mA, T<sub>i</sub>=25°C

Parameter	Cumbal		Unit		
Farameter	Symbol	Min.	Тур.	Max.	Onit
Forward Voltage	$V_{F}$	5.8	-	6.4	V
Luminous Flux	$\Phi_{v}^{[2]}$	500	-	750	lm
Correlated Color Temperature[3]	ССТ	2,700	-	7,000	K
CRI <sup>[4]</sup>	Ra	70 80	-	80 90	-
Viewing Angle	2Θ1/2	-	120	-	deg.
Thermal resistance (J to S)[5]	Rθ <sub>j-s</sub>	-	2.0	-	K/W
ESD Sensitivity(HBM)	-	Class 2	2 JEDEC JS-00	)1-2017	

**Table 4. Absolute Maximum Ratings** 

Parameter	Symbol	Value	Unit
Forward Current	I <sub>F</sub>	800	mA
Power Dissipation	$P_{D}$	5.0	W
Junction Temperature	T <sub>j</sub>	125	°C
Operating Temperature	T <sub>opr</sub>	-40 ~ + 100	°C
Storage Temperature	T <sub>stg</sub>	-40 ~ + 100	°C

#### Notes:

- (1) Seoul Semiconductor maintains a tolerance of  $\pm 7\%$  on flux and power measurements.
- (2)  $\Phi_V$  is the total luminous flux output as measured with an integrating sphere.
- (3) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. Color coordinate:  $\pm 0.005$ , CCT  $\pm 5\%$  tolerance.
- (4) Tolerance is  $\pm 2.0$  on CRI,  $\pm 0.2$  on VF measurements.
- Calculated performance values are for reference only.
- All measurements were made under the standardized environment of Seoul Semiconductor.

Fig 1. Color Spectrum, T<sub>i</sub>=25°C, I<sub>F</sub>=640mA (CRI70)

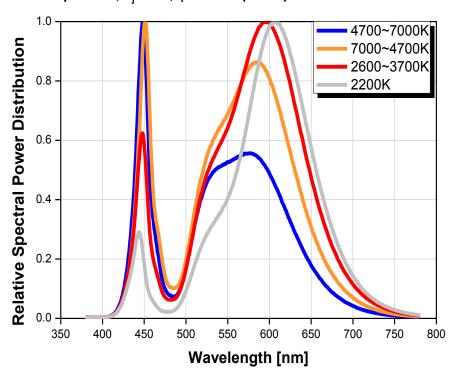


Fig 1. Color Spectrum, T<sub>i</sub>=25°C, I<sub>F</sub>=640mA (CRI80)

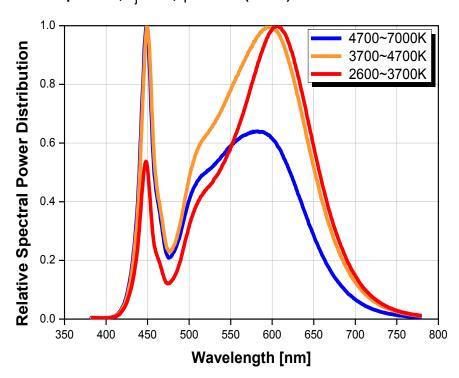


Fig 2. Radiant pattern, T<sub>i</sub>=25°C, I<sub>F</sub>=640mA

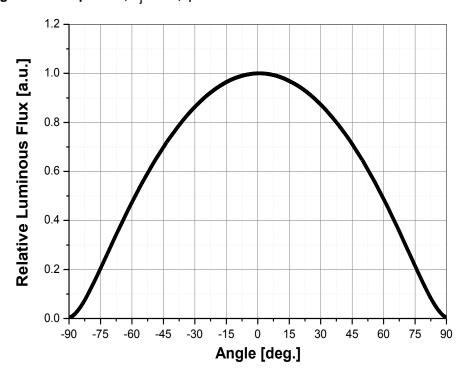


Fig 3. Forward Voltage vs. Forward Current, T<sub>i</sub>=25°C

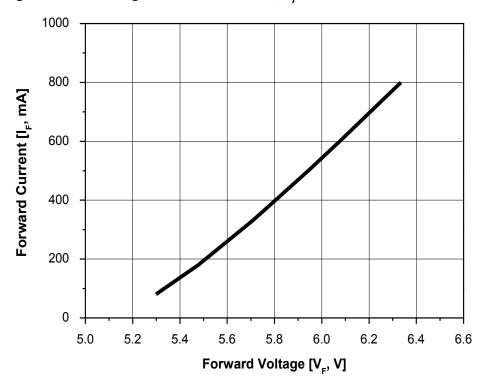


Fig 4. Forward Current vs. Relative Luminous Flux, T<sub>i</sub>=25°C

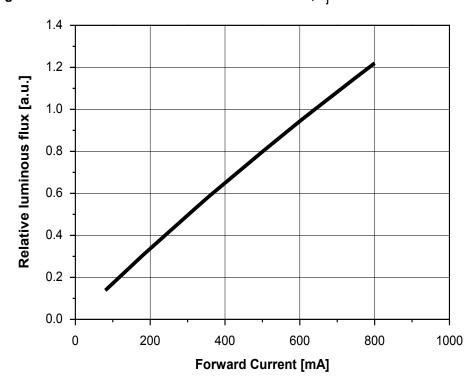
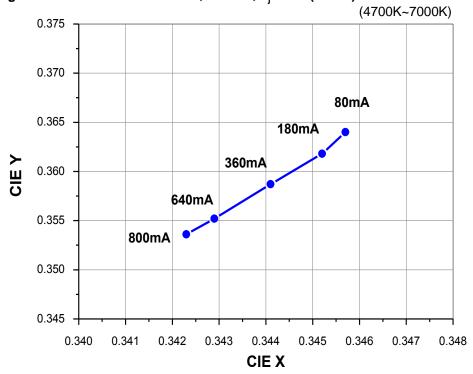




Fig 5. Forward Current vs. CIE X, Y Shift , T<sub>i</sub>=25°C (CRI70)



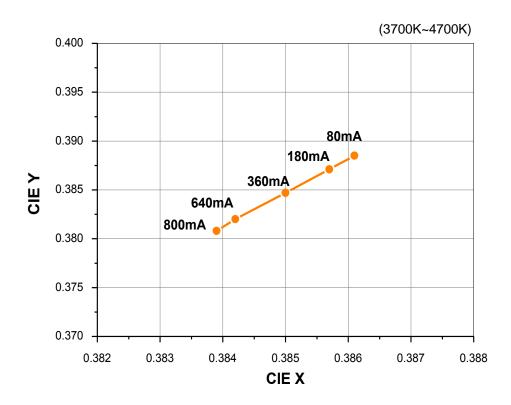
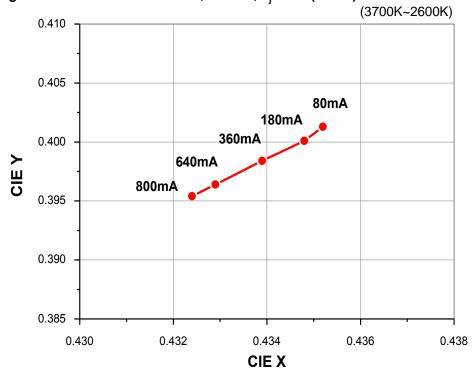




Fig 5. Forward Current vs. CIE X, Y Shift , T<sub>i</sub>=25°C (CRI70)



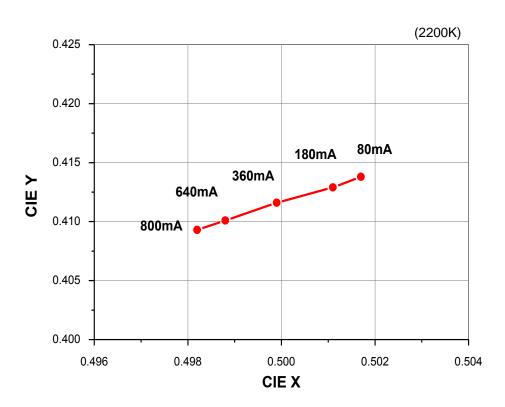
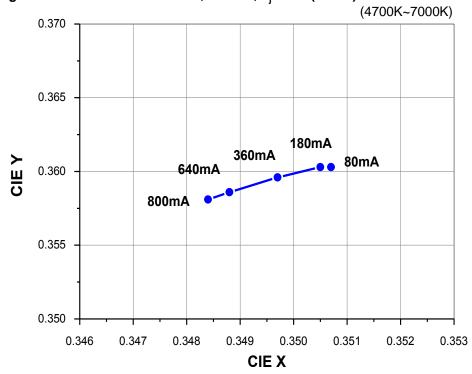


Fig 5. Forward Current vs. CIE X, Y Shift , T<sub>i</sub>=25°C (CRI80)



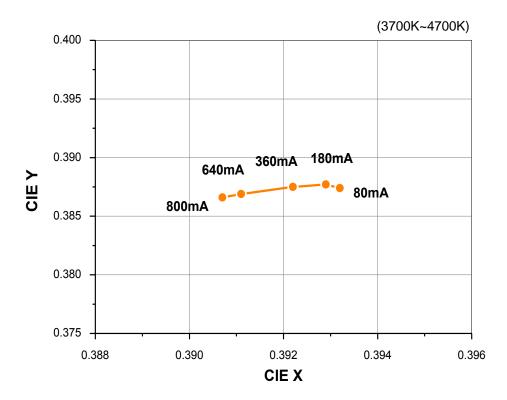




Fig 5. Forward Current vs. CIE X, Y Shift , T<sub>i</sub>=25°C (CRI80)

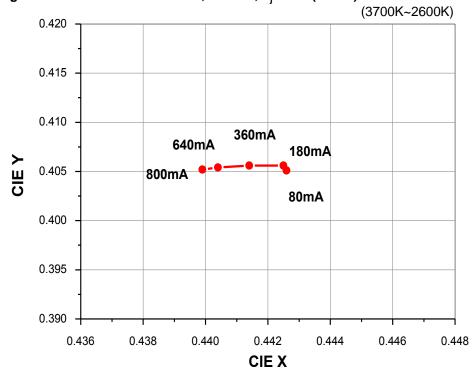


Fig 6. Relative Light Output vs. Junction Temperature, I<sub>F</sub>=640mA

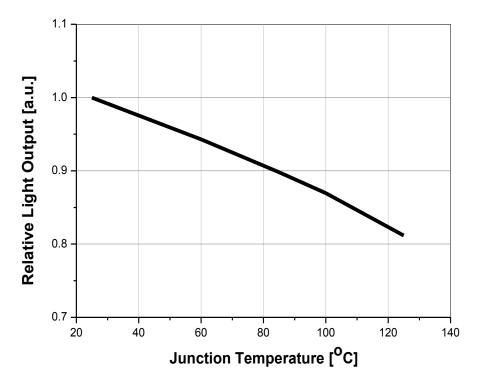


Fig 7. Relative Forward Voltage vs. Junction Temperature, I<sub>F</sub>=640mA

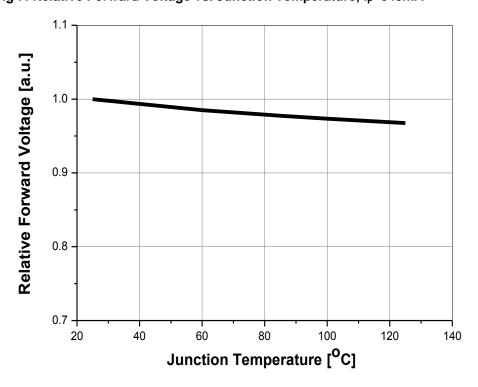
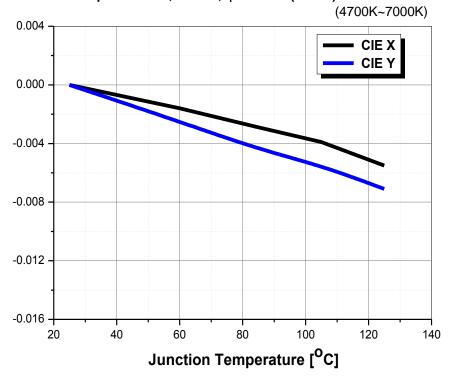




Fig 8. Junction Temp. vs. CIE X, Y Shift, I<sub>F</sub>=640mA (CRI70)



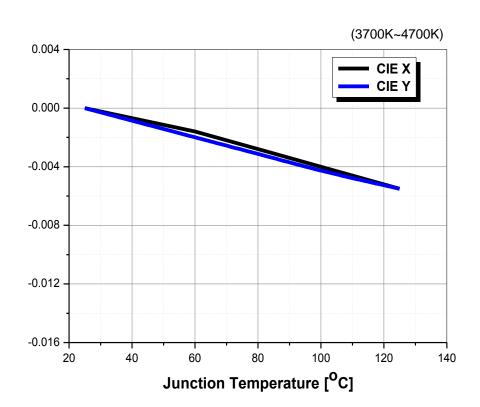
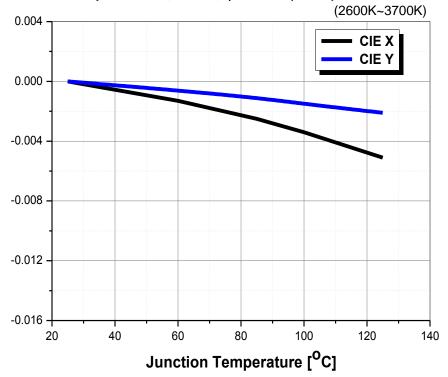


Fig 8. Junction Temp. vs. CIE X, Y Shift, I<sub>F</sub>=640mA (CRI70)



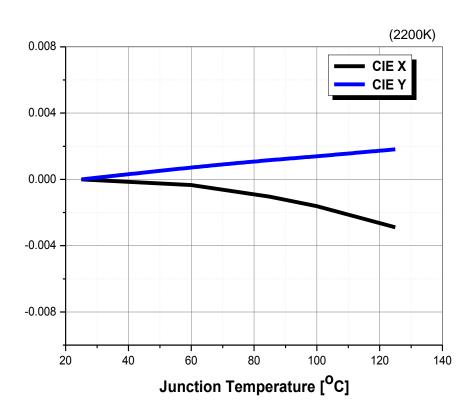
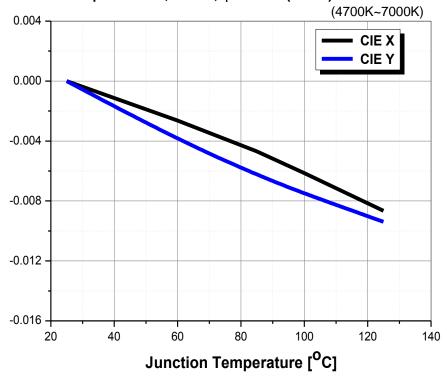


Fig 8. Junction Temp. vs. CIE X, Y Shift, I<sub>F</sub>=640mA (CRI80)



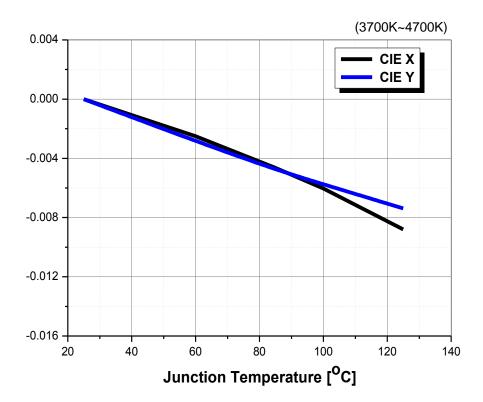


Fig 8. Junction Temp. vs. CIE X, Y Shift, I<sub>F</sub>=640mA (CRI80)

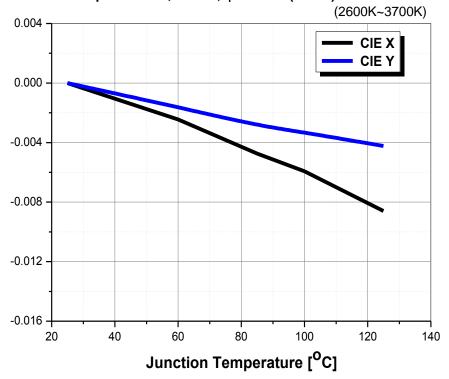
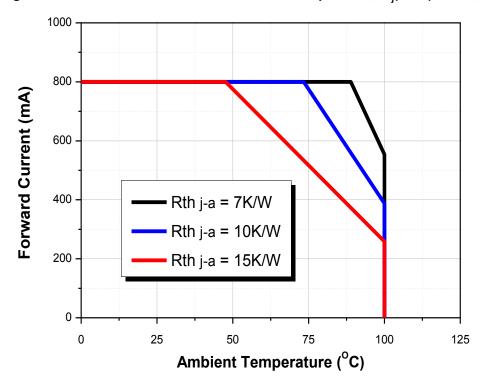




Fig 9. Maximum Forward Current vs. Ambient Temperature, T<sub>i</sub>(max.)=125°C, I<sub>F</sub>=800mA



# **Color Bin Structure**

Table 5. Bin Code description

Part Number	Luminous Flux (lm) I <sub>F</sub> =640mA, T <sub>j</sub> =25°C			Color Chromaticity Coordinate	Forward Voltage(V <sub>f</sub> ) I <sub>F</sub> =640mA, T <sub>j</sub> =25°C			CRI
	Bin Code	Min.	Max.	I <sub>F</sub> =640mA, T <sub>j</sub> =85°C	Bin Code	Min.	Max.	CKI
	V3	500	550	Refer to page. 20 ~ 24	Y8	5.8	6.0	
S1W0-	W1	550	600		Z0	6.0	6.2	
5050xxxx06- 00000000-	W2	600	650		Z2	6.2	6.4	70 80
00002	W3	650	700					. 50
	W4	700	750					

Table 6. Luminous Flux & Forward Voltage rank distribution

CRI	сст	CIE	Flux Rank					VF Rank		
	7000 ~ 6000K	Α	V3	W1	W2	W3	W4	Y8	Z0	Z2
	6000 ~ 5300K	В	V3	W1	W2	W3	W4	Y8	Z0	Z2
	5300 ~ 4700K	С	V3	W1	W2	W3	W4	Y8	Z0	Z2
70	4700 ~ 4200K	D	V3	W1	W2	W3	W4	Y8	Z0	Z2
70	4200 ~ 3700K	E	V3	W1	W2	W3	W4	Y8	Z0	Z2
	3700 ~ 3200K	F	V3	W1	W2	W3	W4	Y8	Z0	Z2
	3200 ~ 2900K	G	V3	W1	W2	W3	W4	Y8	Z0	Z2
	2900 ~ 2600K	Н	V3	W1	W2	W3	W4	Y8	Z0	Z2
	2600 ~ 2200K	K	V3	W1	W2	W3	W4	Y8	Z0	Z2
	7000 ~ 6000K	Α	V3	W1	W2	W3	W4	Y8	Z0	Z2
	6000 ~ 5300K	В	V3	W1	W2	W3	W4	Y8	Z0	Z2
	5300 ~ 4700K	С	V3	W1	W2	W3	W4	Y8	Z0	Z2
80	4200 ~ 3700K	E	V3	W1	W2	W3	W4	Y8	Z0	Z2
	3700 ~ 3200K	F	V3	W1	W2	W3	W4	Y8	Z0	Z2
	3200 ~ 2900K	G	V3	W1	W2	W3	W4	Y8	Z0	Z2
	2900 ~ 2600K	Н	V3	W1	W2	W3	W4	Y8	Z0	Z2

Available ranks
Not yet available ranks

<sup>·</sup> All measurements were made under the standardized environment of Seoul Semiconductor.

## **Color Bin Structure**

Table 5. Bin Code description

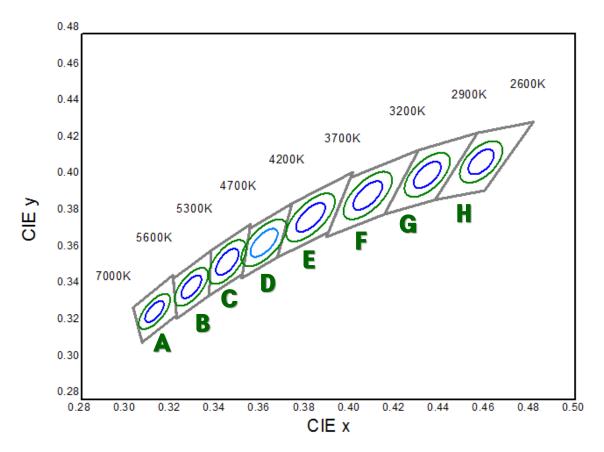
Part Number	Luminous Flux (lm) I <sub>F</sub> =640mA, T <sub>j</sub> =25°C			Color Chromaticity Coordinate	Forward Voltage(V <sub>f</sub> ) I <sub>F</sub> =640mA, T <sub>j</sub> =25°C			CRI
	Bin Code	Min.	Max.	I <sub>F</sub> =640mA, T <sub>j</sub> =85°C	Bin Code	Min.	Max.	OKI
	V3	500	550	Refer to page.	Y8	5.8	6.0	
S1W0-	W1	550	600		Z0	6.0	6.2	
5050xxxx06- 00000000-	W2	600	650		Z2	6.2	6.4	70 80
00002	W3	650	700					
	W4	700	750					

Table 6. Luminous Flux & Forward Voltage rank distribution

CRI	сст	CIE	Rank	PPF [µmol/s] Min.	PPF [µmol/s] Typ.	PPF [µmol/s] Max.	PPE [µmol/J] @640mA
	7000 ~ 6000K	А	W3	9.343	9.484	9.502	3.069
	6000 ~ 5300K	В	W3	9.363	9.429	9.516	3.052
	5300 ~ 4700K	С	W3,W4	9.307	9.359	9.379	3.029
	4700 ~ 4200K	D	W3,W4	9.195	9.276	9.314	2,982
70	4200 ~ 3700K	E	W3,W4	9.025	9.127	9.144	2.954
	3700 ~ 3200K	F	W2,W3	8.812	8.903	8.945	2.881
	3200 ~ 2900K	G	W2,W3	8.446	8.854	8.873	2.864
	2900 ~ 2600K	Н	W1,W2	8.723	8.803	8.883	2.849
	2600 ~ 2200K	К	W1	8.628	8.748	8.765	2.831
	7000 ~ 6000K	Α	W2	9.179	9.242	9.327	2.991
	6000 ~ 5300K	В	W2	9.024	9.096	9.115	2.944
	5300 ~ 4700K	С	W2	8.924	8.966	9.003	2.913
80	4200 ~ 3700K	E	W2	8.748	8.811	8.828	2.852
	3700 ~ 3200K	F	W1,W2	8.629	8.682	8.723	2.809
	3200 ~ 2900K	G	W1,W2	8.496	8.563	8.581	2.771
	2900 ~ 2600K	Н	W1,W2	8.407	8.465	8.542	2.747

## **Color Bin Structure**

# CIE Chromaticity Diagram $T_j$ =85°C, $I_F$ =640mA

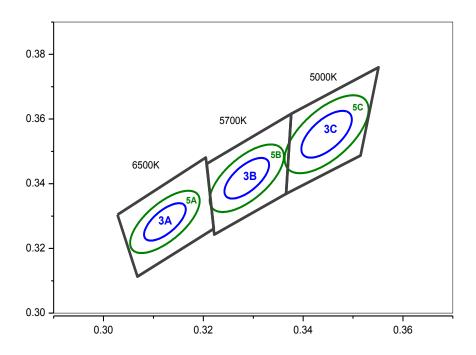


#### \*Notes:

- Energy Star binning applied to all 2600~7000K.
- $\bullet$  Measurement Uncertainty of the Color Coordinates :  $\pm~0.005$

# **Color Bin Structure**

## CIE Chromaticity Diagram (Cool white), $T_j=85$ °C, $I_F=640$ mA

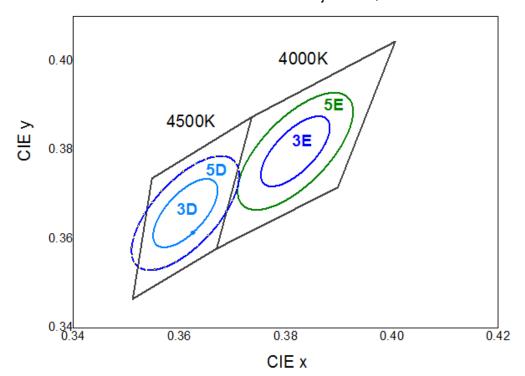


6500l	K 3Step	5700I	K 3Step	5000K 3Step		
	3A		3B		3C	
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553	
Major Axis a	0.0066	Major Axis a	0.0071	Major Axis a	0.0081	
Minor Axis b	0.0027	Minor Axis b	0.003	Minor Axis b	0.0035	
Ellipse	58	Ellipse	59	Ellipse Rotation Angle	60	
Rotation Angle	Rotation Angle		Rotation Angle			

6500	K 5Step	57001	K 5Step	5000K 5Step		
	5A		5B		5C	
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553	
Major Axis a	0.0110	Major Axis a	0.0118	Major Axis a	0.0135	
Minor Axis b	0.0045	Minor Axis b	0.0050	Minor Axis b	0.0058	
Ellipse Rotation Angle	58	Ellipse Rotation Angle	59	Ellipse Rotation Angle	60	

# **Color Bin Structure**

## CIE Chromaticity Diagram (Neutral white), T<sub>i</sub>=85°C, I<sub>F</sub>=640mA



4500K 4Step

3D			
Center point	0.3611 : 0.3658		
Major Axis a	0.009		
Minor Axis b	0.0039		
Ellipse			
Rotation Angle	55		

4000K 3Step

3E			
Center point	0.3818 : 0.3797		
Major Axis a	0.00940		
Minor Axis b	0.00400		
Ellipse Rotation Angle	53		

4500K 5Step

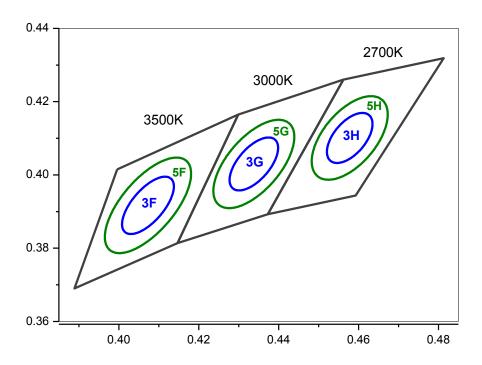
5	D
Center point	0.3611 : 0.3658
Major Axis a	0.015
Minor Axis b	0.0065
Ellipse Rotation Angle	55

4000K 5Step

5E			
Center point	0.3818 : 0.3797		
Major Axis a	0.0157		
Minor Axis b	0.0067		
Ellipse Rotation Angle	53		

## **Color Bin Structure**

## CIE Chromaticity Diagram (Warm white), T<sub>i</sub>=85°C, I<sub>F</sub>=640mA

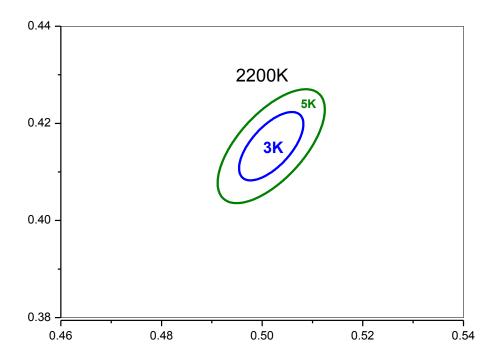


3500	K 3Step	3000	K 3Step	27001	K 3Step
	3F		3 <b>G</b>		3H
Center point	0.4073 : 0.3917	Center point	0.4338 : 0.4030	Center point	0.4578 : 0.4101
Major Axis a	0.0093	Major Axis a	0.0085	Major Axis a	0.0079
Minor Axis b	0.0041	Minor Axis b	0.0041	Minor Axis b	0.0041
Ellipse Rotation Angle	53	Ellipse Rotation Angle	53	Ellipse Rotation Angle	54

3500	K 5Step	3000K 5Step		2700K 5Step	
	5F	5G		5G 5H	
Center point	0.4073 : 0.3917	Center point	0.4338 : 0.4030	Center point	0.4578 : 0.4101
Major Axis a	0.0155	Major Axis a	0.0142	Major Axis a	0.0132
Minor Axis b	0.0068	Minor Axis b	0.0068	Minor Axis b	0.0068
Ellipse	53	Ellipse	53	Ellipse	 54
Rotation Angle	33	Rotation Angle	33	Rotation Angle	J <del>4</del>

## **Color Bin Structure**

# CIE Chromaticity Diagram (Warm white), $T_j$ =85°C, $I_F$ =640mA



#### 2200K 3Step

3K		
Center point	0.5018 : 0.4153	
Major Axis a	0.00863	
Minor Axis b	0.00398	
Ellipse Rotation Angle	49	

#### 2200K 5Step

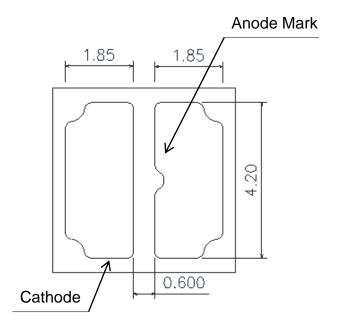
5K			
Center point	0.5018 : 0.4153		
Major Axis a	0.01438		
Minor Axis b	0.00663		
Ellipse	49		
Rotation Angle	<del>4</del> 9		

## **Mechanical Dimensions**

## < Top View >

# 5.00 Cathode Mark

## < Bottom View >



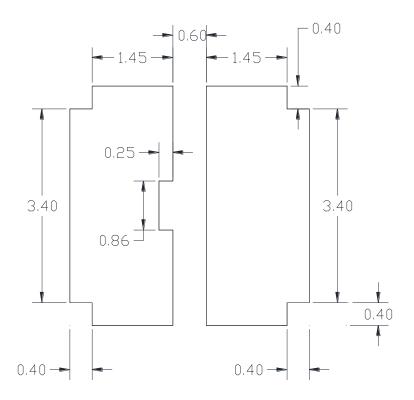
## < Side view>

$\sim$	
~ t	
C~ 1	
1 - 1	
~ b	
- C.J.	

#### Notes:

- (1) All dimensions are in millimeters.
- (2) Scale: none
- (3) Undefined tolerance is  $\pm 0.2$ mm

## **Recommended Solder Pad**



#### Notes:

- (1) All dimensions are in millimeters.
- (2) Scale: none
- (3) Undefined tolerance is  $\pm 0.2$ mm
- (4) This drawing without tolerances are for reference only.

## **Reflow Soldering Characteristics**

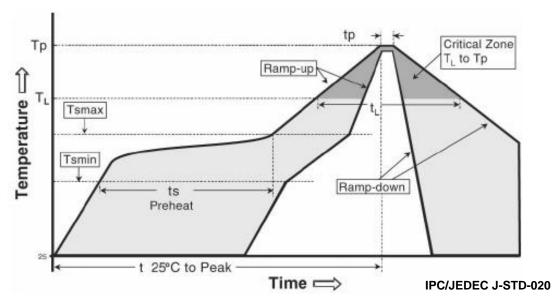


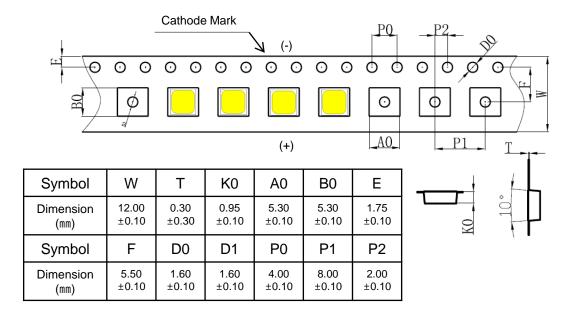
Table 7.

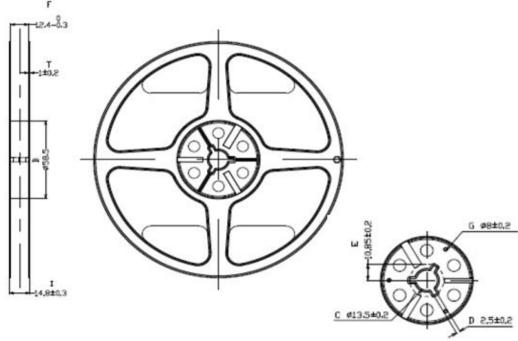
Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T <sub>smax</sub> to T <sub>p</sub> )	3° C/second max.	3° C/second max.
Preheat - Temperature Min (T <sub>smin</sub> ) - Temperature Max (T <sub>smax</sub> ) - Time (T <sub>smin</sub> to T <sub>smax</sub> ) (t <sub>s</sub> )	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-180 seconds
Time maintained above: - Temperature (T <sub>L</sub> ) - Time (t <sub>L</sub> )	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak Temperature (T <sub>p</sub> )	215℃	260℃
Time within 5°C of actual Peak Temperature (t <sub>p</sub> )2	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

#### Caution

- (1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
- (2) Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
- (3) Die slug is to be soldered.
- (4) When soldering, do not put stress on the LEDs during heating.
- (5) After soldering, do not warp the circuit board.

# **Emitter Tape & Reel Packaging**





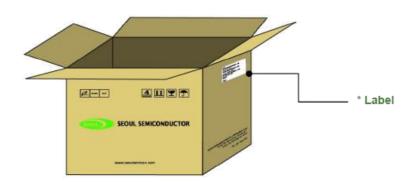
#### Notes:

- (1) Quantity : 7 inch reel  $\,$  type ( 1,000 pcs / Reel  $\pm$  1pcs)
- (2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be  $\pm 0.2 \text{mm}$
- (3) Adhesion Strength of Cover Tape: Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of 10° to the carrier tape
- (4) Package : P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package.

# **Emitter Tape & Reel Packaging**









## **Product Nomenclature**

**Table 8. Part Numbering System** 

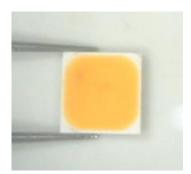
Part Number Code	Description	Part Number	Value
<b>X</b> <sub>1</sub>	Company	S	Seoul Semiconductor
X <sub>2</sub>	Level of Integration	1	Discrete LED
X <sub>3</sub> X <sub>4</sub>	Technology	W0	White General
X <sub>5</sub> X <sub>6</sub> X <sub>7</sub> X <sub>8</sub>	Dimension	5050	5.0x5.0mm
X <sub>9</sub> X <sub>10</sub>	сст	xx	65: 6500K 57: 5700K 50: 5000K 40: 4000K 35: 3500K 30: 3000K 27: 2700K
X <sub>11</sub> X <sub>12</sub>	CRI	xx	CRI70 CRI80
X <sub>13</sub> X <sub>14</sub>	Vf 06		
X <sub>15</sub> X <sub>16</sub> X <sub>17</sub>	Characteristic code Flux Rank	000	
X <sub>18</sub> X <sub>19</sub> X <sub>20</sub>	Characteristic code Vf Rank	000	
X <sub>21</sub> X <sub>22</sub>	Characteristic code Color Step	xx	3S: 3step ellipse 5S: 5step ellipse
X <sub>23</sub> X <sub>24</sub>	Туре	00	
X <sub>25</sub> X <sub>26</sub> X <sub>27</sub>	Internal code	002	



## **Handling of Silicone Resin for LEDs**

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.





- (2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.
- (3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.
- (4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

- (5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin.

  Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.
- (6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this. product with acid or sulfur material in sealed space.

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## **Precaution for Use**

(1) Storage

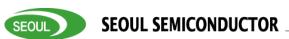
To avoid the moisture penetration, we recommend store in a dry box with a desiccant. The recommended storage temperature range is 5°C to 30°C and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use SMT techniques properly when you solder the LED as separation of the lens may affect the light output efficiency.

Pay attention to the following:

- a. Recommend conditions after opening the package
  - Sealing / Temperature : 5 ~ 40°C Humidity : less than RH30%
- b. If the package has been opened more than 4 week(MSL\_2a) or the color of the desiccant changes, components should be dried for 10-12hr at 60±5°C
- (3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.
- (4) Do not rapidly cool device after soldering.
- (5) Components should not be mounted on warped (non coplanar) portion of PCB.
- (6) Radioactive exposure is not considered for the products listed here in.
- (7) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.
- (8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.
- (9) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.
- (10) LEDs must be stored properly to maintain the device. If the LEDs are stored for 3 months or more after being shipped from Seoul Semiconductor. A sealed container with a nitrogen atmosphere should be used for storage.
- (11) The appearance and specifications of the product may be modified for improvement without notice.
- (12) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.



## **Precaution for Use**

- (13) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.
- (14) The slug is electrically isolated.
- (15) Attaching LEDs, do not use adhesives that outgas organic vapor.
- (16) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.
- (17) LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.
- a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

#### Environmental controls:

- Humidity control (ESD gets worse in a dry environment)



## **Precaution for Use**

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package
  (If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package (shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.
- c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:
  - A surge protection circuit
  - An appropriately rated over voltage protection device
  - A current limiting device



## **Company Information**

#### Published by

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#### **Company Information**

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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